

## SUPPLEMENTARY INFORMATION

### **Probabilistic computing using $\text{Cu}_{0.1}\text{Te}_{0.9}/\text{HfO}_2/\text{Pt}$ diffusive memristors**

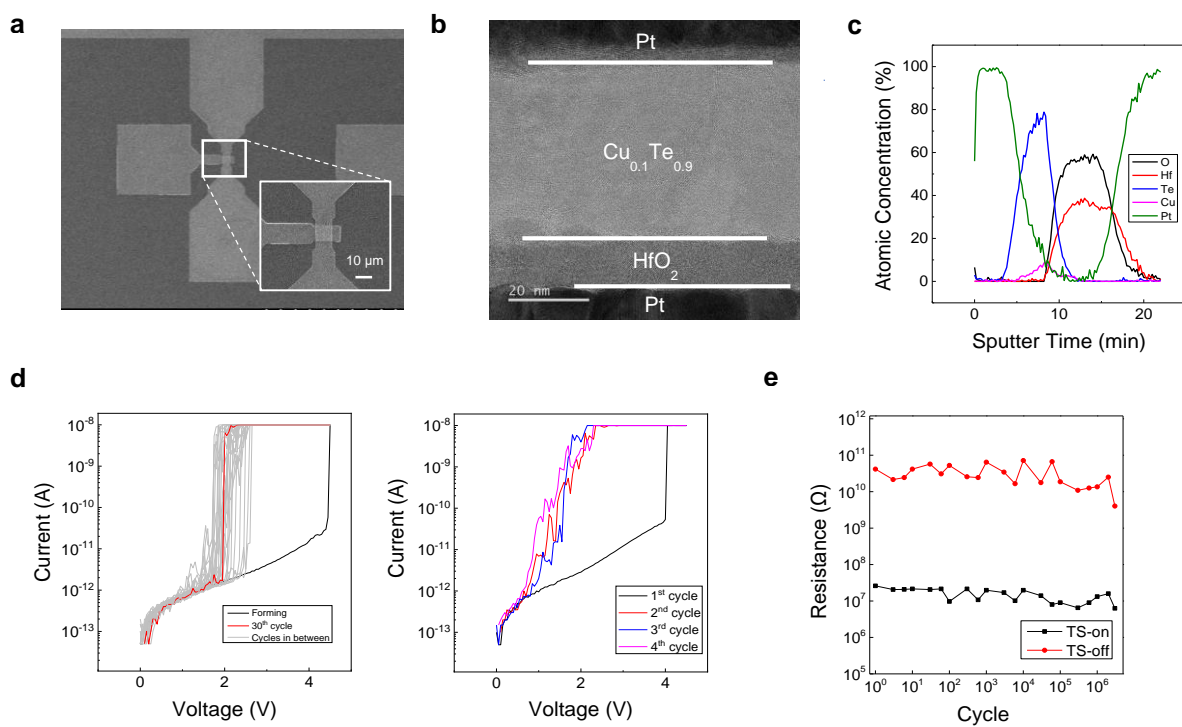
Kyung Seok Woo<sup>1</sup>, Jaehyun Kim<sup>1</sup>, Janguk Han<sup>1</sup>, Woohyun Kim<sup>1</sup>, Yoon Ho Jang<sup>1</sup> and Cheol Seong Hwang<sup>1\*</sup>

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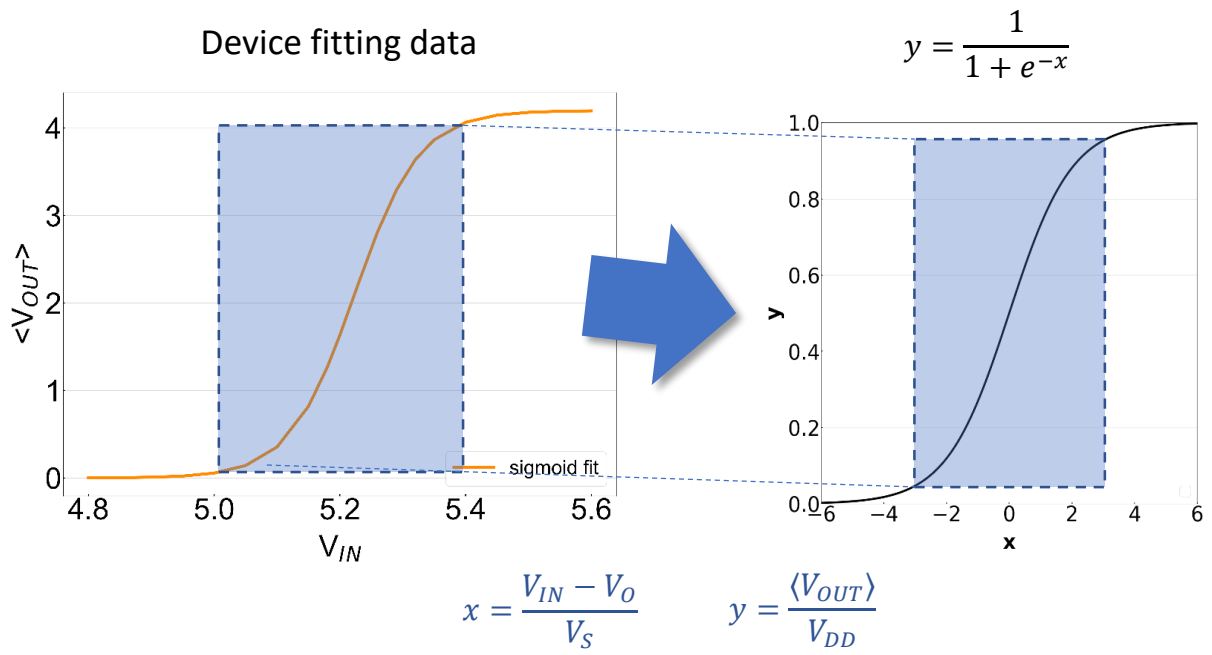
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## Supplementary Figures



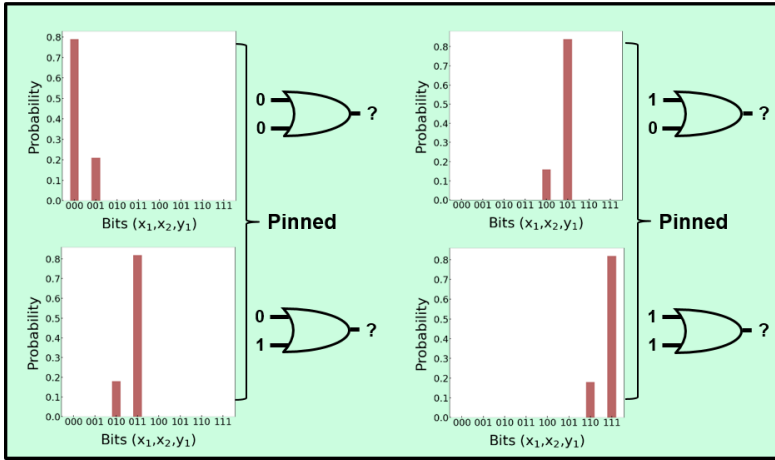
**Supplementary Figure S1:** a) SEM image of the cross-point structure. b) Cross sectional high-resolution TEM image. c) AES depth profile of the CTHP device. d) I-V curves of TS (left panel,  $x = 0.1$ ) and RS (right panel,  $x = 0.2$ ) behaviors of the  $\text{Cu}_x\text{Te}_{1-x}$ -based memristor.<sup>1</sup> e) Cycling endurance of the CTHP device.



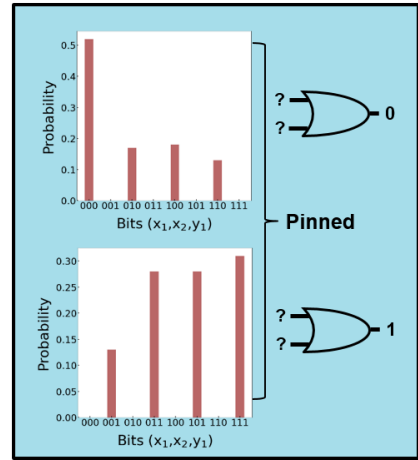
**Supplementary Figure S2:** Normalization of the device fitting data to sigmoid function.



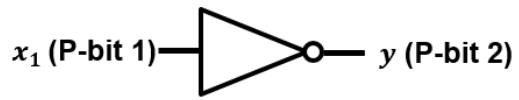
**i. Forward operation**



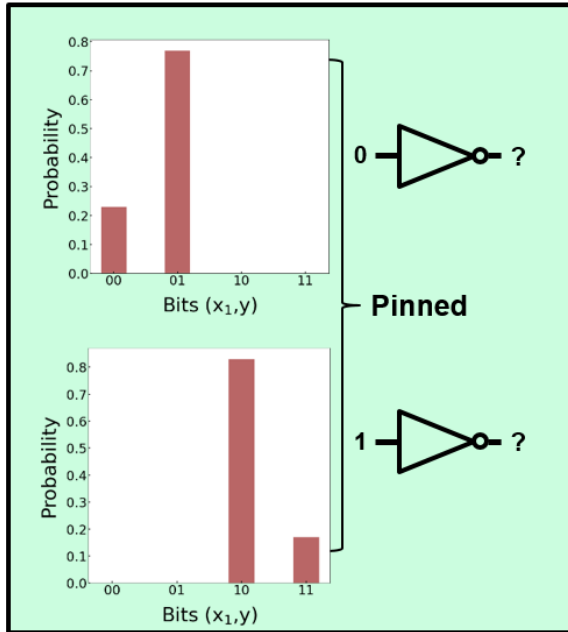
**ii. Inverted operation**



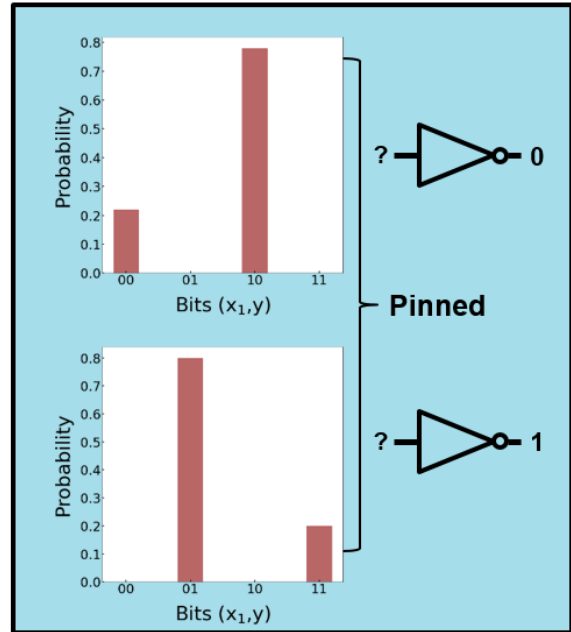
**Supplementary Figure S3:**  $x_1$  OR  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



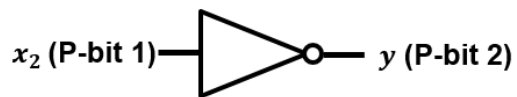
**i. Forward operation**



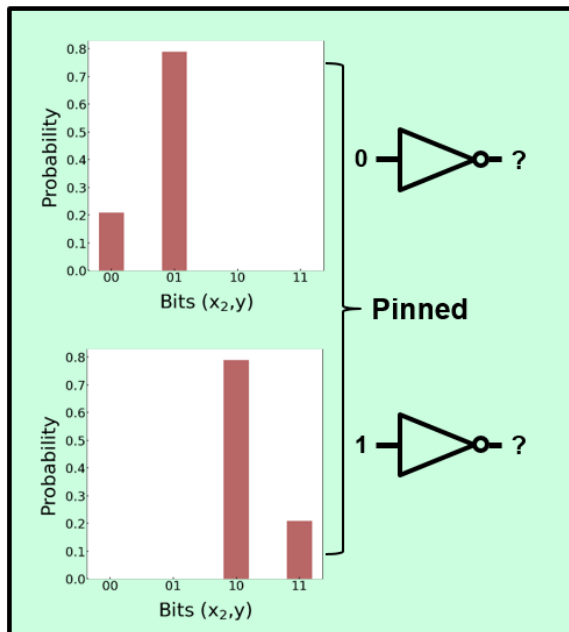
**ii. Inverted operation**



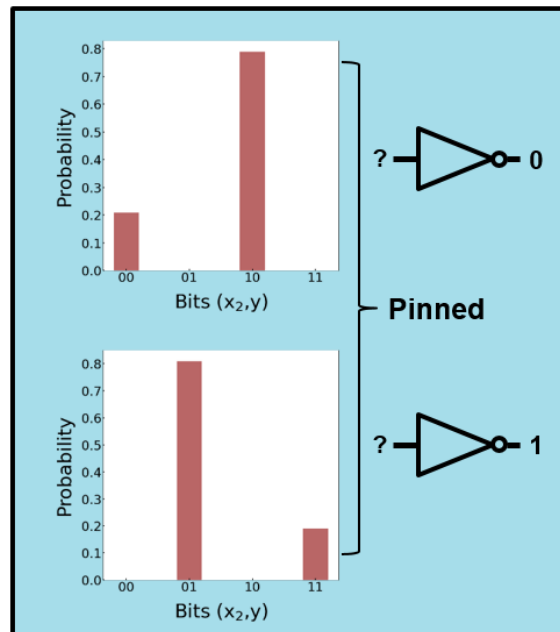
**Supplementary Figure S4: NOT  $x_1$ .** Forward and reverse operations are shown in panels i and ii, respectively.



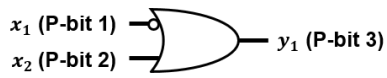
**i. Forward operation**



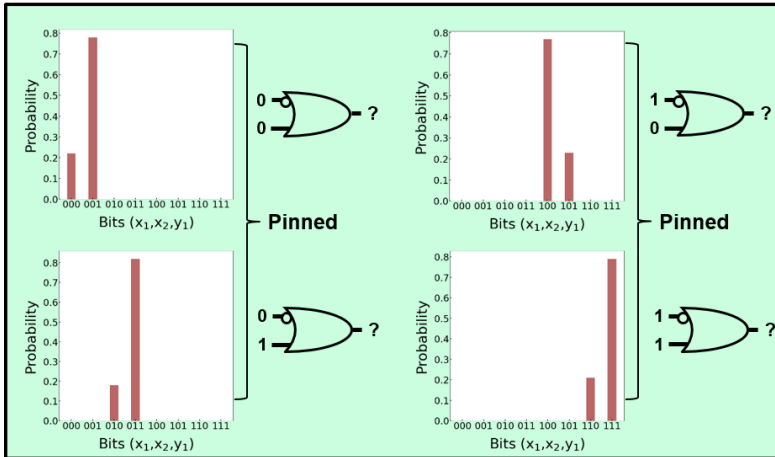
**ii. Inverted operation**



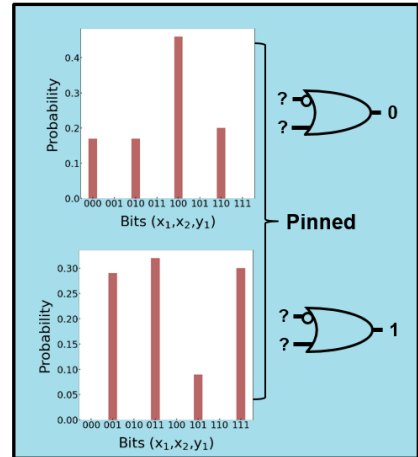
**Supplementary Figure S5: NOT  $x_2$ .** Forward and reverse operations are shown in panels i and ii, respectively.



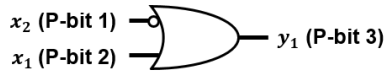
**i. Forward operation**



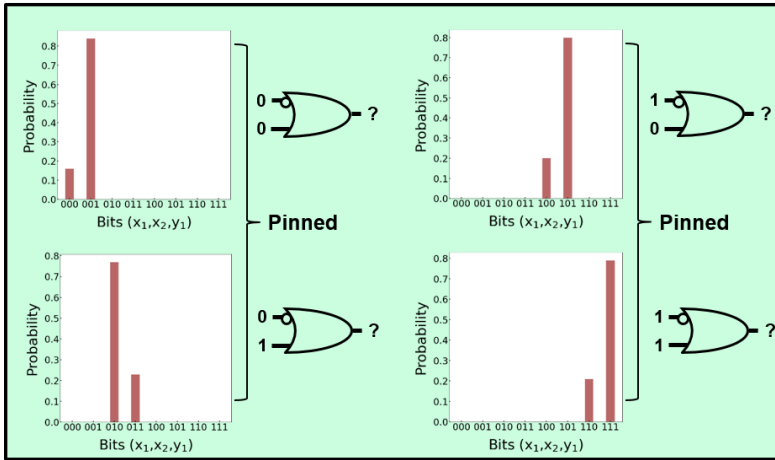
**ii. Inverted operation**



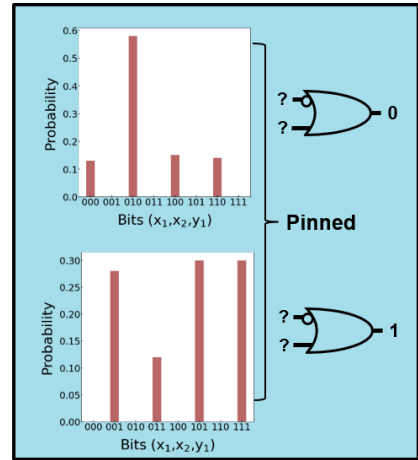
**Supplementary Figure S6:**  $x_1$  IMP  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



**i. Forward operation**

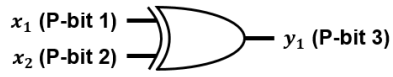


**ii. Inverted operation**

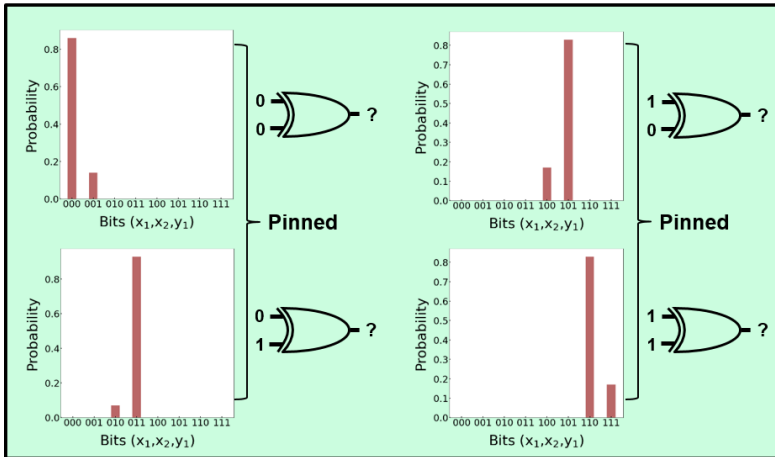


**Supplementary Figure S7:**  $x_2$  IMP  $x_1$ . Forward and reverse operations are shown in panels i and ii, respectively.

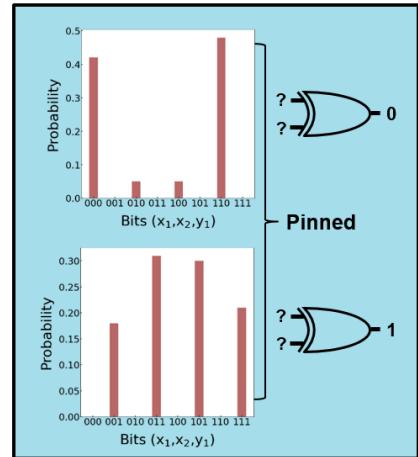




**Forward operation**



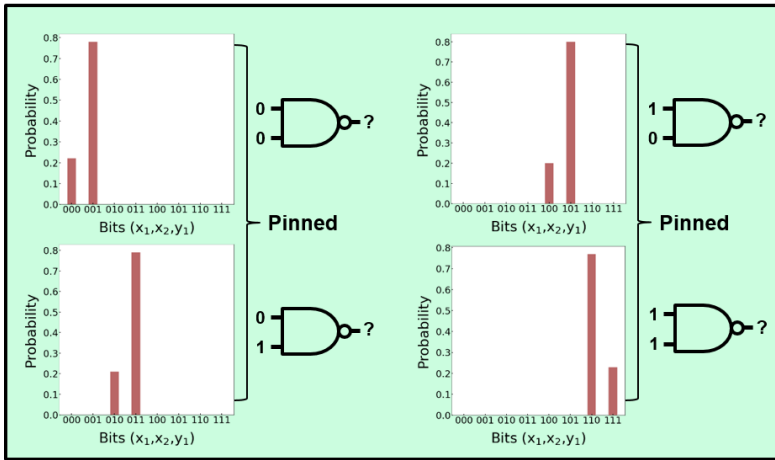
**Inverted operation**



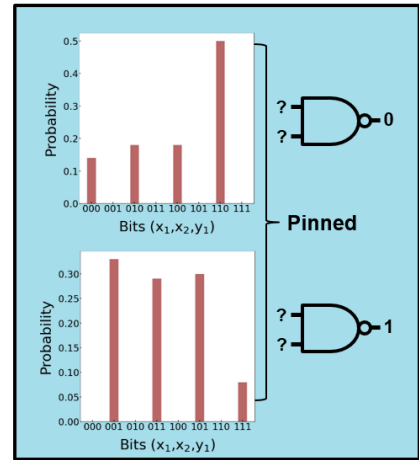
**Supplementary Figure S8:**  $x_1$  XOR  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



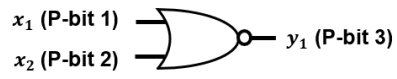
**i. Forward operation**



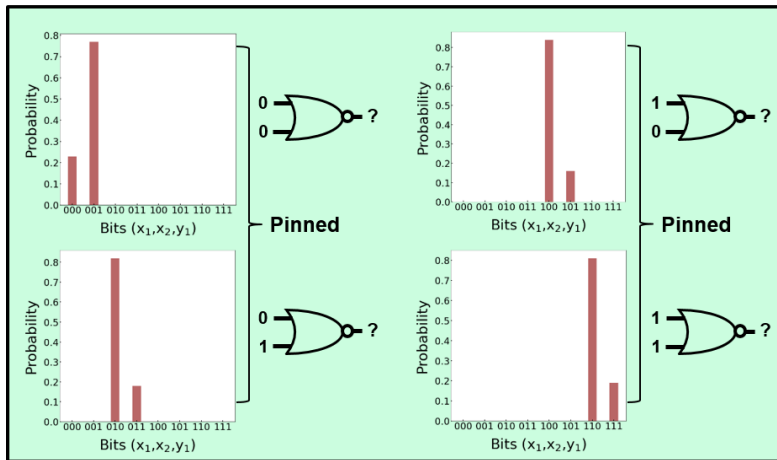
**ii. Inverted operation**



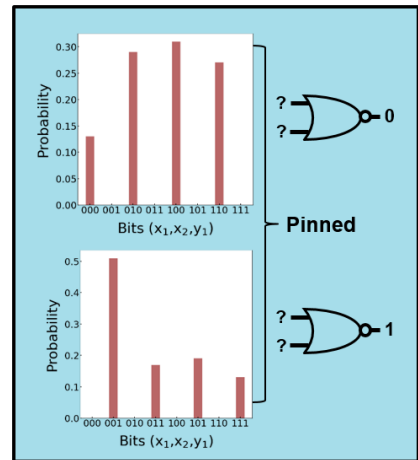
**Supplementary Figure S9:**  $x_1$  NAND  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



**i. Forward operation**



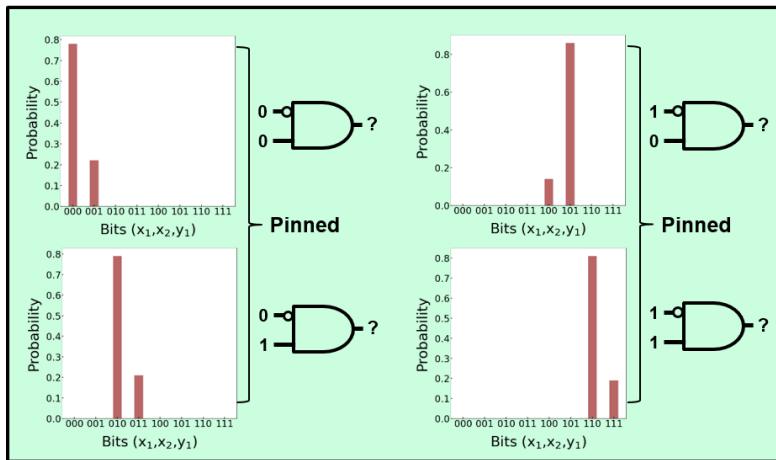
**ii. Inverted operation**



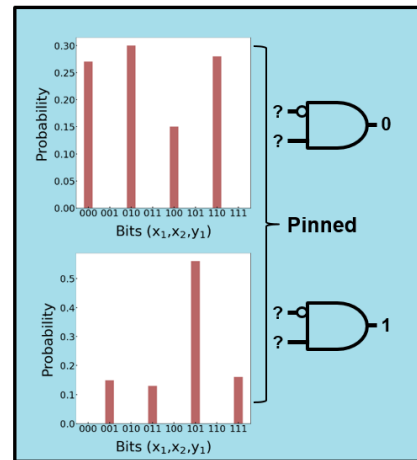
**Supplementary Figure S10:**  $x_1$  NOR  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



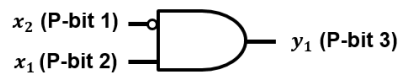
**i. Forward operation**



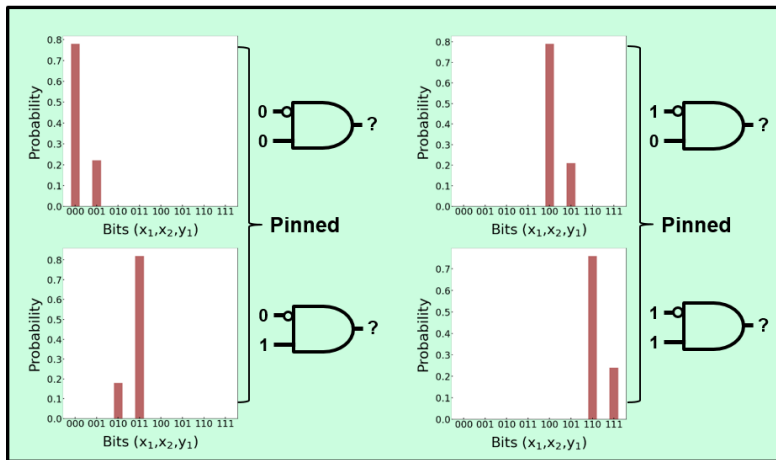
**ii. Inverted operation**



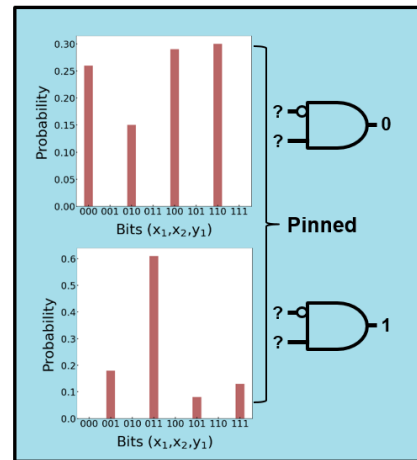
**Supplementary Figure S11:**  $x_1$  NIMP  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



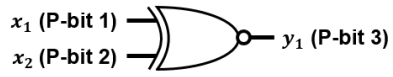
**i. Forward operation**



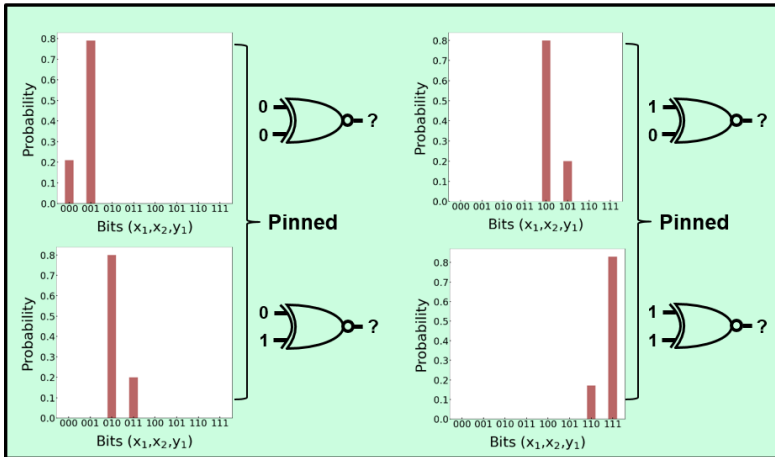
**ii. Inverted operation**



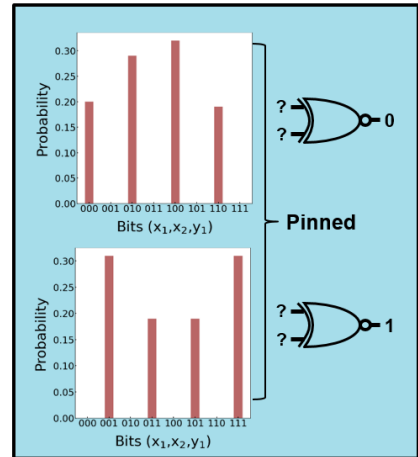
**Supplementary Figure S12:**  $x_2$  NIMP  $x_1$ . Forward and reverse operations are shown in panels i and ii, respectively.



**i. Forward operation**



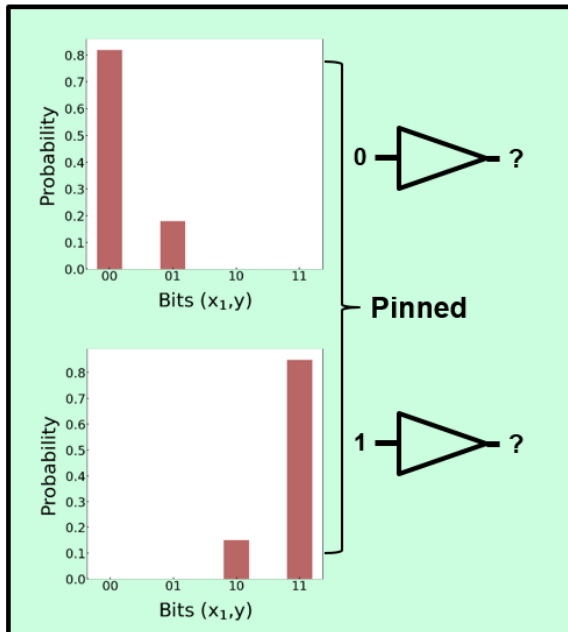
**ii. Inverted operation**



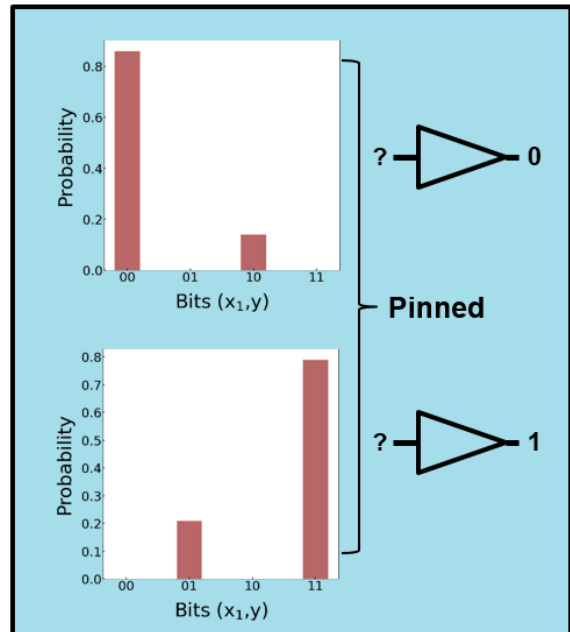
**Supplementary Figure S13:**  $x_1$  XNOR  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



**i. Forward operation**



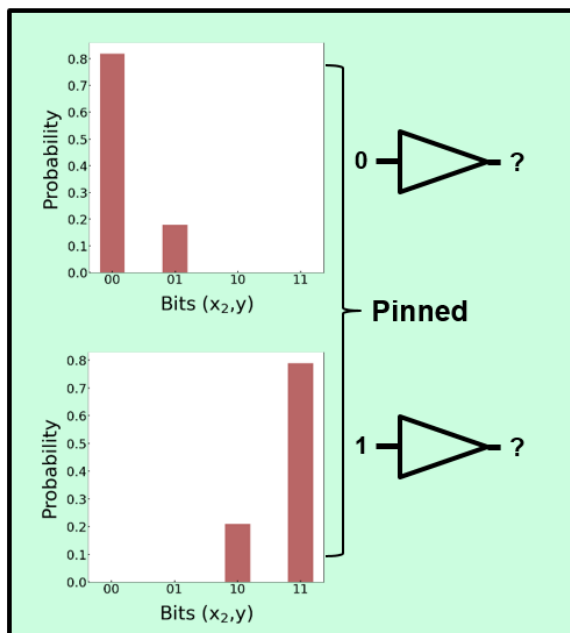
**ii. Inverted operation**



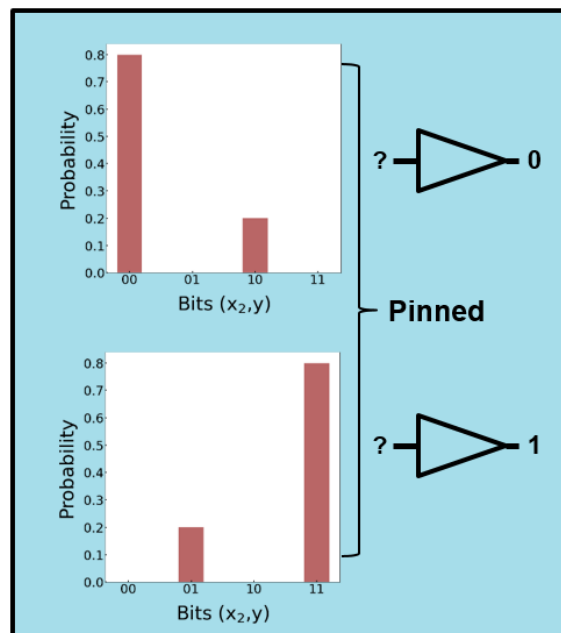
**Supplementary Figure S14:**  $x_1$ . Forward and reverse operations are shown in panels i and ii, respectively.



**i. Forward operation**



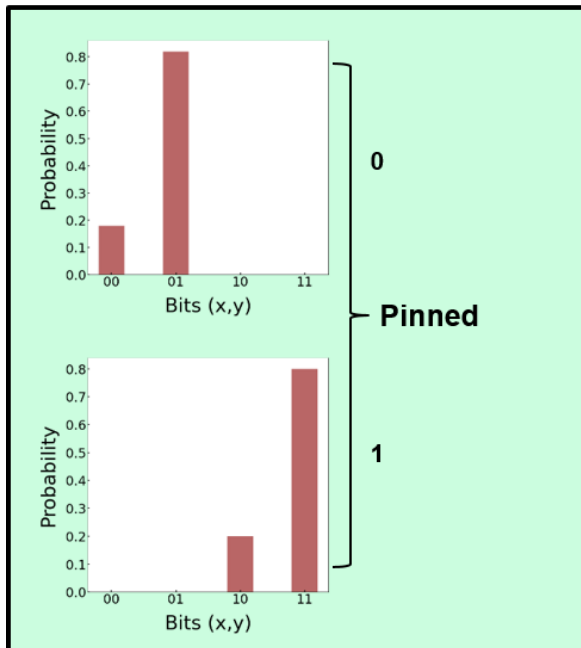
**ii. Inverted operation**



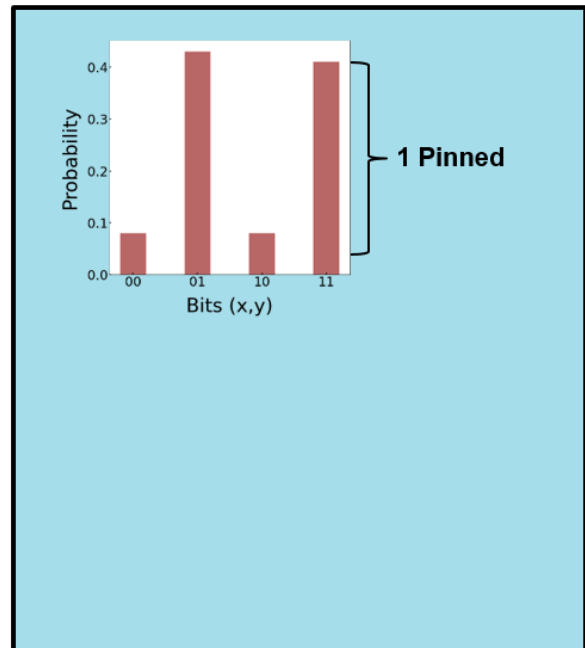
**Supplementary Figure S15:**  $x_2$ . Forward and reverse operations are shown in panels i and ii, respectively.



### i. Forward operation

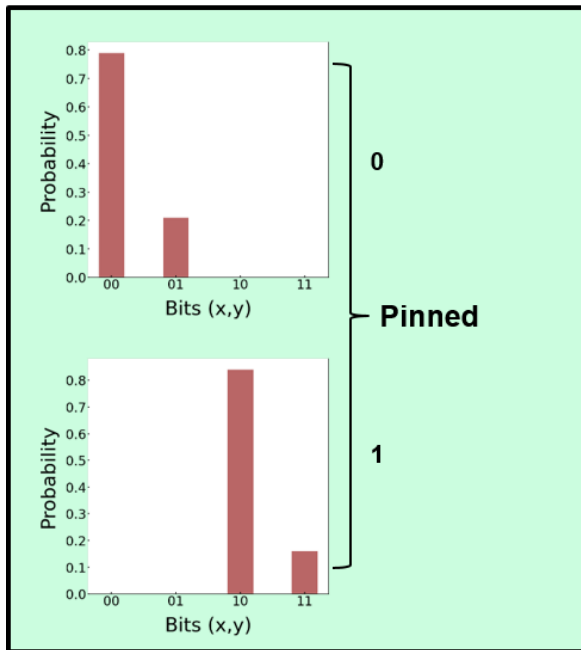


### ii. Inverted operation

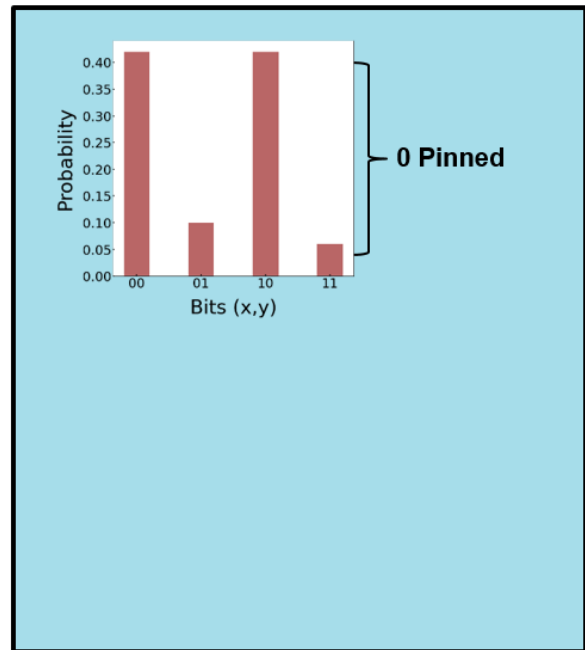


**Supplementary Figure S16: TRUE.** Forward and reverse operations are shown in panels i and ii, respectively.

### i. Forward operation



### ii. Inverted operation



**Supplementary Figure S17: FALSE.** Forward and reverse operations are shown in panels i and ii, respectively.



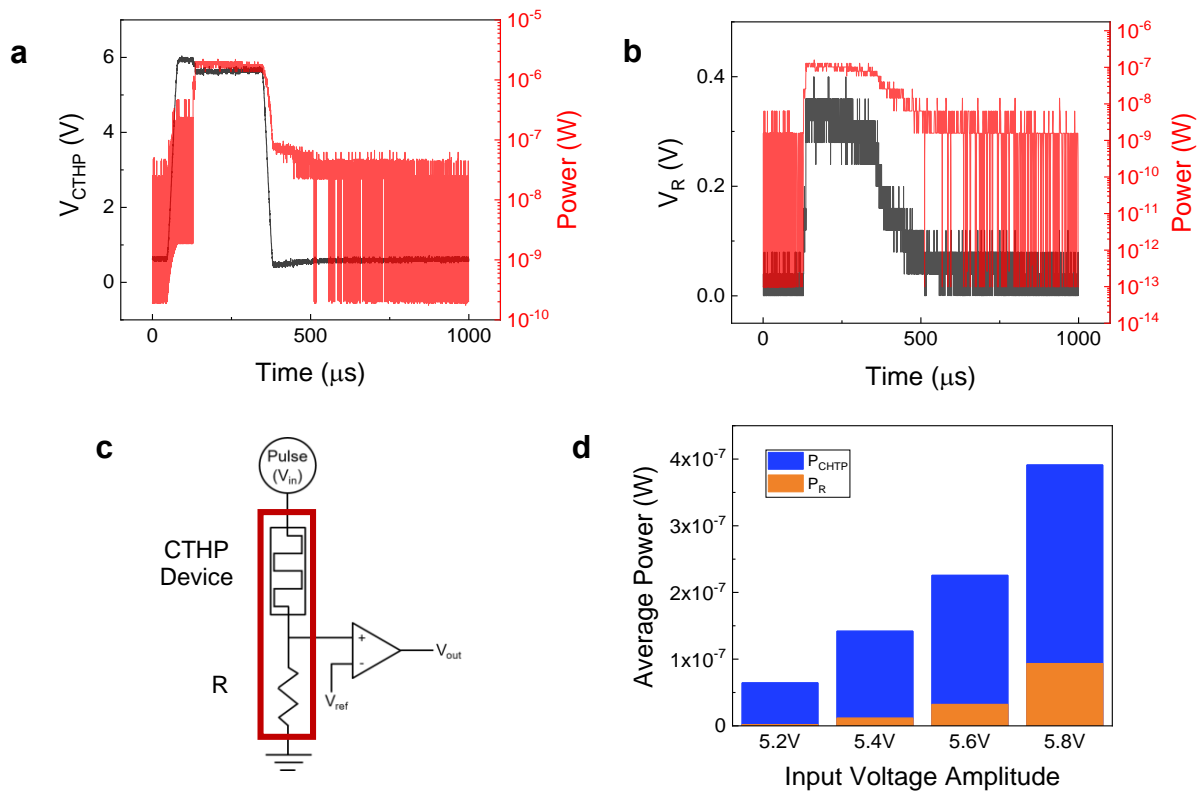
A	B	C <sub>in</sub>	S	C <sub>out</sub>
0	0	0	0	0
0	0	1	1	0
0	1	0	1	0
0	1	1	0	1
1	0	0	1	0
1	0	1	0	1
1	1	0	0	1
1	1	1	1	1

$$O + S = A + B + I$$

$$E = I_0(O + S - A - B - I)^2$$

$$E(C_p, \dots, C_1, S_Q, \dots, S_0, A_R, \dots, A_0, B_T, \dots, B_0, I_U, \dots, I_0) = I_0 \left[ \left( \sum_{p=1}^P 2^p C_p \right) + \left( \sum_{q=0}^Q 2^q S_q \right) - \left( \sum_{r=0}^R 2^r A_r \right) - \left( \sum_{t=0}^T 2^t B_t \right) - \left( \sum_{u=0}^U 2^u I_u \right) \right]^2$$

**Supplementary Figure S18:** A design for a full adder using a five-p-bit network.



**Supplementary Figure S19:** Power consumption calculation results of the CTHP p-bit circuit. a) Power consumption of the CTHP device. b) Power consumption of the series resistor. c) The CTHP p-bit circuit design used in the analysis. d) Power consumption at different input voltage pulse amplitudes, averaged over 40 cycles.

## Supplementary Tables

**Supplementary Table 1:** Definitions of cost functions and the resulting input functions for

all 16 Boolean logic operations. ( $I_0 = 1$ )

Logic functions	Definitions of cost functions	Input functions
AND	$y_1 = x_1x_2$ $E(x_1, x_2, y_1) = (x_1x_2 - y_1)^2$ $= x_1^2x_2^2 - 2x_1x_2y_1 + y_1^2 = x_1x_2 - 2x_1x_2y_1 + y_1$	$I_{x_1} = -x_2 + 2x_2y_1$ $I_{x_2} = -x_1 + 2x_1y_1$ $I_{y_1} = 2x_1x_2 - 1$
OR	$y_1 = x_1 + x_2 - x_1x_2$ $E(x_1, x_2, y_1) = (x_1 + x_2 - x_1x_2 - y_1)^2$ $= x_1 - 2x_1y_1 + x_2 - 2x_2y_1 - x_1x_2 + 2x_1x_2y_1 + y_1$	$I_{x_1} = -1 + 2y_1 + x_2 - 2x_2y_1$ $I_{x_2} = -1 + 2y_1 + x_1 - 2x_1y_1$ $I_{y_1} = -2x_1 + 2x_2 - 2x_1x_2 - 1$
NOT	$y = 1 - x$ $E(x, y) = (x + y - 1)^2$ $= 2xy - x - y + 1$	$I_x = -2y + 1$ $I_y = -2x + 1$
IMP	$y_1 = (1 - x_1) + x_2 - (1 - x_1)x_2$ $= 1 - x_1 + x_1x_2$ $E(x_1, x_2, y_1) = (1 - x_1 + x_1x_2 - y_1)^2$ $= 1 - x_1 + x_1x_2 - y_1 + 2x_1y_1 - 2x_1x_2y_1$	$I_{x_1} = -1 + 2x_2 + 2y_1 - 4x_2y_1$ $I_{x_2} = 2x_1 - 4x_1y_1 - 1 + 2y_1$ $I_{y_1} = 2x_1 - 4x_1x_2 + 2x_2 + 1$
XOR	$y_1 = (x_1 - x_2)^2$ $= x_1 - 2x_1x_2 + x_2$ $E(x_1, x_2, y_1) = (x_1 - 2x_1x_2 + x_2 - y_1)^2$ $= x_1 - 2x_1x_2 - 2x_1y_1 + 4x_1x_2y_1 + x_2 - 2x_2y_1 + y$	$I_{x_1} = -1 + 2x_2 + 2y_1 - 4x_2y_1$ $I_{x_2} = 2x_1 - 4x_1y_1 - 1 + 2y_1$ $I_{y_1} = 2x_1 - 4x_1x_2 + 2x_2 + 1$
NAND	$y_1 = 1 - x_1\text{AND}x_2$ $= 1 - x_1x_2$ $E(x_1, x_2, y_1) = (1 - x_1x_2 - y_1)^2$ $= 1 - x_1x_2 + 2x_1x_2y_1 - y_1$	$I_{x_1} = x_2 - 2x_2y_1$ $I_{x_2} = x_1 - 2x_1y_1$ $I_{y_1} = -2x_1x_2 + 1$
NOR	$y_1 = 1 - x_1\text{OR}x_2$ $= 1 - x_1 - x_2 + x_1x_2$ $E(x_1, x_2, y_1) = (1 - x_1 - x_2 + x_1x_2 - y_1)^2$ $= 1 - x_1 + 2x_1y_1 - x_2 + 2x_2y_1 + x_1x_2 - 2x_1x_2y_1 - y_1$	$I_{x_1} = 1 - 2y_1 - x_2 + 2x_2y_1$ $I_{x_2} = 1 - 2y_1 - x_1 + 2x_1y_1$ $I_{y_1} = -2x_1 - 2x_2 + 2x_1x_2 + 1$
NIMP	$y_1 = 1 - x_1\text{IMP}x_2$ $= x_1 - x_1x_2$ $E(x_1, x_2, y_1) = (x_1 - x_1x_2 - y_1)^2$ $= x_1 - x_1x_2 + y_1 - 2x_1y_1 + 2x_1x_2y_1$	$I_{x_1} = -1 + x_2 + 2y_1 - 2x_2y_1$ $I_{x_2} = x_1 - 2x_1y_1$ $I_{y_1} = -1 + 2x_1 - 2x_1x_2$
XNOR	$y_1 = 1 - x_1\text{XOR}x_2$ $= 1 - x_1 + 2x_1x_2 - x_2$	$I_{x_1} = 1 - 2x_2 - 2y_1 + 4x_2y_1$ $I_{x_2} = -2x_1 + 4x_1y_1 + 1 - 2y_1$

	$E(x_1, x_2, y_1) = (1 - x_1 + 2x_1x_2 - x_2 - y_1)^2$ $= 1 - x_1 + 2x_1x_2 + 2x_1y_1 - 4x_1x_2y_1 - x_2 + 2x_2y_1 - y$	$I_{y_1} = -2x_1 + 4x_1x_2 - 2x_2 + 1$
$x$ (TRANSFER)	$y = x$ $E(x, y) = (x - y)^2$ $= x^2 - 2xy + y^2$ $= x - 2xy + y$	$I_x = -1 + 2x$ $I_y = -1 + 2x$
TRUE	$y = 1$ $E(y) = (1 - y)^2$ $= 1 - 2y + y^2$ $= 1 - y$	$I_x = 0$ $I_{y_1} = 1$
FALSE	$y = 0$ $E(y) = (-y)^2$ $= y^2$ $= y$	$I_x = 0$ $I_y = -1$

## Supplementary Note 1. Ising model

According to the Ising model, the total energy of the spin system is defined by Ising Hamiltonian,

$$E = -\sum_{(i,j)} J_{ij} x_i x_j - \sum_i h x_i \quad (\text{S1})$$

, where  $x_i, x_j$  are spins of each site having values of either -1 or 1,  $J_{ij}$  is an interaction strength between two spins, and  $h$  is the external magnetic field.<sup>2</sup> The first term stands for the internal interaction energy between the spins, and the second term is the energy of the individual spins interacting with the external field. The probability of the system to have the energy value  $E$  is calculated by the Boltzmann distribution,  $P_i = \exp(-\beta E_i)/Z$ , where  $E_i$  is the energy of the system,  $\beta$  is  $(kT)^{-1}$ , and  $Z$  is a partition function,  $\sum_i \exp(-\beta E_i)$ .<sup>3</sup> Accordingly, the spin configuration with the lowest energy occurs with the highest probability. The underlying idea of the Ising model is further extended to a Hopfield network in the machine learning field.

## Supplementary References

1. Woo, K. S. *et al.* A High-Speed True Random Number Generator Based on a  $\text{Cu}_x\text{Te}_{1-x}$  Diffusive Memristor. *Adv. Intell. Syst.* **3**, (2021).
2. Neal, R. M. Connectionist learning of belief networks. *Artif. Intell.* **56**, 71–113 (1992).
3. Camsari, K. Y., Faria, R., Sutton, B. M. & Datta, S. Stochastic p-bits for invertible logic. *Phys. Rev. X* **7**, 31014 (2017).